

5 x 7 mm, 3.0, 3.3 & 5.0 Volt, HCMOS or Clipped Sinewave, Precision TCXO/TCVCXO

Product Features

Tight stability performance

(+/0.2 ppm) over Industrial Temperatures (-40°C to +85°C) (+/0.10 ppm) over Commercial Temperatures (0°C to 70°C)

- · Available in 10 pad and 14 DIP configurations (Contact factory for 14 DIP)
- 3.0 V, 3.3 V and 5.0 V versions
- Low phase noise performance
- · Tri-state Function standard
- Low G-sensitivity (0.6 ppb/G) version available





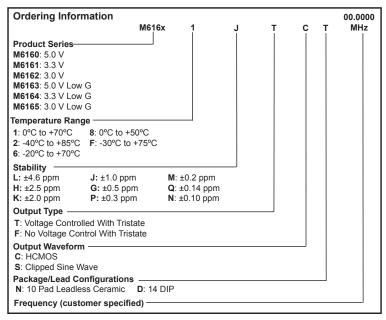
Product Description

MtronPTI's M616x Series TCXO's and TCVCXO's provide design engineers with low voltage, surface mount products with extremely tight stability (to 0.10 ppm) over temperature and time. Specially processed crystals enable the M616x to achieve consistent long-term stability and minimal frequency shift after reflow. This processing also achieves excellent g-sensitivity (0.6 ppb/g). The low phase noise (-155 dBc/Hz at 100 kHz) makes the M616x ideal for the design engineer working on all types of systems as the reference timing source. Ten pad SMT and 14-pin DIP compatible versions available.

Product Applications

The M616x Series is ideally suited for a wide range of applications such as GPS, military, avionics, test and measurement, WLAN, WiMax base stations, point to point/multi-point radios, medical equipment, frequency synthesis, frequency translation and land mobile radio. Standard output for the M616x series is HCMOS compatible or clipped sinewave. The product is ideally suited for battery and remote applications where it draws as little as 1.5 mA of current with a 3.3 volt supply at 13 MHz. This low power consumption provides an advantage over similarly specified ovenized oscillators for power-sensitive applications. The M616x series offers ±9.2 ppm minimum pull range with excellent tuning linearity performance for critical PLL applications. This series is available in frequencies from 8 to 40MHz and selective frequencies up to 52 MHz.

Product Ordering Information



M6160Sxxx, M6161Sxxx, M6162Sxxx, M6163Sxxx, M6164Sxxx & M6165Sxxx - Contact factory for datasheets.



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Performance Characteristics

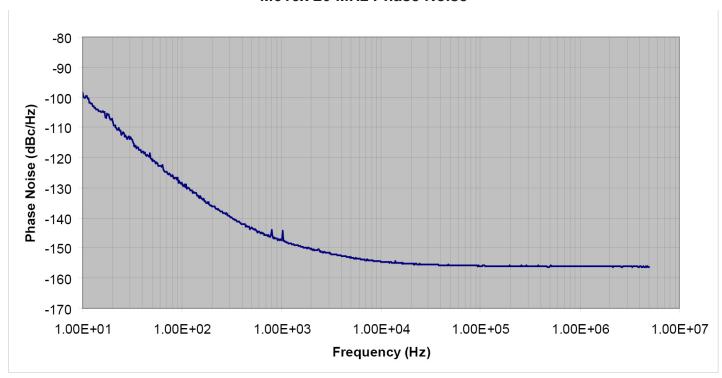
	Parameter	Symbol	Min.	Тур.	Max.	Units	Conditions/Notes
	Frequency Range	Fo	8		52	MHz	Contact factory above 40 MHz
	Operating Temperature	T_A	-40			°C	See Ordering Information
	Storage Temperature	T _{STG}	-55		+125	℃	
	Frequency Tolerance @ +25 ℃		-1.0		+1.0	ppm	For TCXO only
	Frequency Stability		S	See Orderir	ng Information		(Fmax – Fmin)/2
	Stability Vs. Reflow		-1.0		+1.0	ppm	
	Frequency Vs. Supply			±0.02	±0.1	ppm	For 5% supply voltage variation
	Frequency Vs. Load			±0.02	±0.1	ppm	For 5% load variation
	Aging (First Year)		-1.0		+1.0	ppm	F ₀ ≤ 20 MHz
	Aging (First Year)		-2.0		+2.0	ppm	F ₀ > 20 MHz
	Aging (10 Year)		-3.0		+3.0	ppm	$F_0 \le 20 \text{ MHz (Includes first year)}$
	Aging (10 Year)		-5.0		+5.0	ppm	F ₀ > 20 MHz (Includes first year)
	Supply Voltage Tolerance		-5.0		+5.0	%	See Ordering Information
	Supply Current (I _D)		2.0		3.0	mA	HCMOS output at 13 MHz
			3.0		4.0	mA	HCMOS output at 26 MHz
			5.5		6.5	mA	HCMOS output at 52 MHz
s			1.3		1.9	mA	Clipped sinewave output at 13 MHz
o			1.7 2.8		2.3 3.5	mA mA	Clipped sinewave output at 26 MHz
ati	Output Logic Levels	V _{OL}	2.8		20	%V _S	Clipped sinewave output at 52 MHz $I_{OH}/I_{OL} = \pm 4$ mA, Vs = +3.0 V
ij	(HCMOS)		80		20	% ∨ s % ∨ s	$I_{OH}/I_{OL} = \pm 4 \text{ mA}, \text{ VS} = +3.0 \text{ V}$ $I_{OH}/I_{OL} = \pm 4 \text{ mA}, \text{ VS} = +3.0 \text{ V}$
Specifications	Output Level	V _{OH}	1.0			V _{pk-pk}	$F_0 \le 40 \text{ MHz}$
	(Clipped Sinewave)		0.8			V_{pk-pk}	$F_0 > 40 \text{ MHz}$
ica	Waveform Symmetry		40		60	%	Ref. to ½ V _{S.} HCMOS only
Electrical	Rise/Fall Time				6.5	ns	Ref. 10% to 90%. HCMOS only
Ele	Output Load			15		pF	HCMOS output
	·			10/10		Kohm/pF	Clipped sinewave output
	Frequency Adjustment		-5.0		+5.0	ppm	Over Control Voltage Range
	G-Sensitivity			0.6		ppb/g	
	Control Voltage Range		0.3		2.7	Volts	For $V_S = 3.0$
			0.3		3.0	Volts	For $V_S = 3.3$
			0.5		4.5	Volts	For $V_S = 5.0$
	Input Leakage Current		-50		+50	μΑ	
	Input Resistance		100			Kohm	
	Linearity Modulation Bandwidth		0 1411-		5	%	
	Tristate Function		2 kHz 70			%V _S	Output enabled. Logic "1" or "Open"
	Tristate Function		70		30	%V _S	Output disabled. Logic "0" or "GND"
	Tristate Leakage Current		-100		+100	μA	Output disabled. Logic o of GIVD
	Phase Noise		100	-98	+100	dBc/Hz	10 Hz Offset
	(Typical 20 MHz CMOS)			-125		dBc/Hz	100 Hz Offset
	(Typical 20 Mil 12 CMOS)						1 KHz Offset
				-145 -154		dBc/Hz	10 KHz Offset
				-154 -156		dBc/Hz dBc/Hz	10 kHz Offset
Н		<u> </u>	<u> </u>	-136		UDC/FIZ	TOO KITZ OHSEL
Environmental	Shock	MIL-STD-2	02 Metho	d 213 Co	100 g		
ner	Vibration	MIL-STD-2			10 g from 10 to 2000 Hz		
۱ň	Solderability	EIAJ-STD-	,	<u></u>	10 9 110111 10 10 2000 112		
/irc	Package	5.0 x 7.0 m		nd DIP		RoHS Compliant	
Ë	Max Soldering Conditions	See solder					
_	wax soluening conditions						



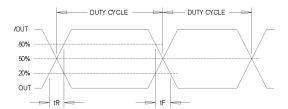
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Phase Noise Plot

M616x 20 MHz Phase Noise



Output Waveform (HCMOS Output)

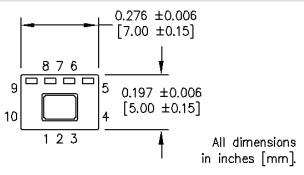


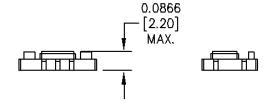


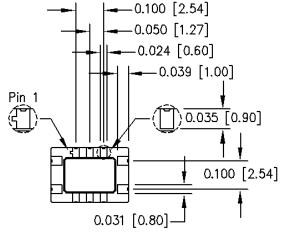
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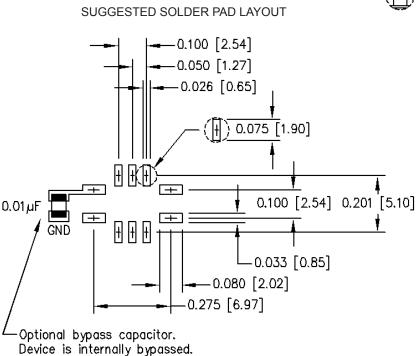
Product Dimension & Pinout Information - Package Code N (10 Pad)

Pin Connections				
Function	Pad			
N/C - Do Not Connect	1			
N/C - Do Not Connect	2			
N/C - Do Not Connect	3			
Ground	4			
Output	5			
N/C - Do Not Connect	6			
N/C - Do Not Connect	7			
Tristate	8			
Supply Voltage (V _s)	9			
Control Voltage	10			











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Handling Information

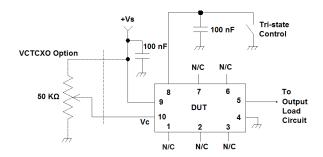
Although protection circuitry has been designed into the M616x oscillator, proper precautions should be taken to avoid exposure to electrostatic discharge (ESD) during handling and mounting. MtronPTI utilizes a human-body model (HBM) and a charged-device model (CDM) for ESD-susceptibility testing and protection design evaluation. ESD voltage thresholds are dependent on the circuit parameters used to define the mode. Although no industry-wide standard has been adopted for the CDM, a standard HBM (resistance = 1500 Ω , capacitance = 100 pF) is widely used and therefore can be used for comparison purposes. The HBM ESD threshold presented here was obtained using these circuit parameters.

Model	ESD Threshold, Minimum	Unit
Human Body	1500*	V
Charged Device	1500*	V





Typical Test Circuits



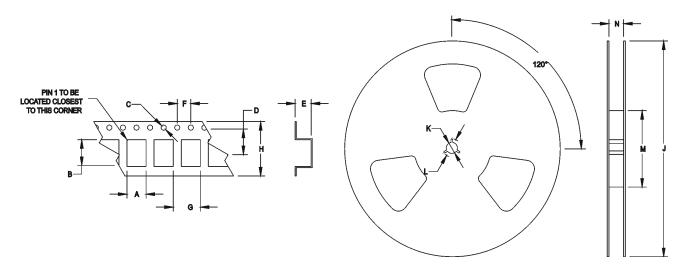
Test Circuit - N Package With Tri-State



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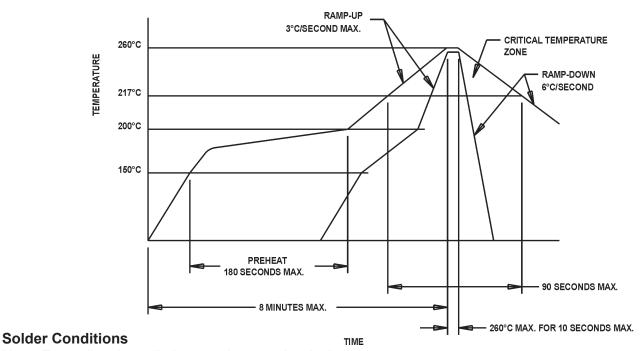
Tape & Reel Specifications

(all measurements are in mm)	Α	В	С	D	E	F	G	Н	J	K	L	M	N
M616x	5.40	7.40	1.55	7.50	2.60	2.00	4.00	16.00	330	13.00	20.20	100	16.40



Standard Tape and Reel: 1000 parts per reel

Maximum Soldering Conditions



Note: Exceeding these limits may damage the device.



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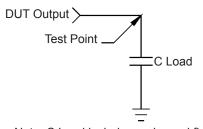
Quality Parameters

Environmental Specifications/Qualification Testing Performed on the M616x TCXO/TCVCXO							
Test	Test Method	Test Condition					
Electrical Characteristics	Internal Specification	Per Specification					
Frequency vs. Temperature	Internal Specification	Per Specification					
Mechanical Shock	MIL-STD-202, Method 213, C	100 g, 6 ms					
Vibration	MIL-STD-202, Method 201-204	10 g from 10-2000 Hz					
Thermal Cycle	MIL-STD-883, Method 1010, B	-55 Deg. C to +125 Deg. C, 15 minute Dwell, 10 cycles					
Aging	Internal Specification	168 Hours at 105 Degrees C					
Gross Leak	MIL-STD-202, Method 112	30 Second Immersion (Crystal Only)					
Fine Leak	MIL-STD-202, Method 112	Must meet 1x10 ⁻⁸ (Crystal Only)					
Solderability	MIL-STD-883, Method 2003	8 Hour Steam Age – Must Exhibit 95% coverage					
Resistance to Solvents	MIL-STD-883, Method 2015	Three 1 minute soaks					
Physical Dimensions	MIL-STD-883, Method 2016	Per Specification					
Internal Visual	Internal Specification	Per Internal Specification					

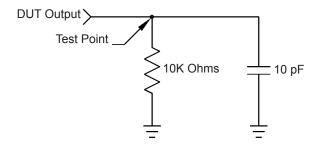
Load Circuit

Load Circuit #2 - HCMOS Output

Load Circuit #7 - Clipped Sinewave Output



Note: C Load includes probe and fixturing.



Product Revision Table

Date	Revision	PCN Number	Details of Revision

For custom products or additional specifications contact our sales team at 800.762.8800 (toll free) or 605.665.9321

For more information on this product visit the MtronPTI website at www.mtronpti.com